
Example 2.6c 4H-SiC is doped with $2 \times 10^{17} \text{ cm}^{-3}$ nitrogen donor atoms ($E_c - E_d = 90 \text{ meV}$). Use $N_c = 4 \times 10^{20} \text{ cm}^{-3}$.

- a) Calculate the electron density at 300 K.
- b) Calculate the hole density at 300 K after adding $2 \times 10^{18} \text{ cm}^{-3}$ aluminum acceptor atoms ($E_a - E_v = 220 \text{ meV}$) Use $N_v = 1.6 \times 10^{20} \text{ cm}^{-3}$.

Solution

- a) First we calculate N^*

$$N^* = \frac{N_c}{2} \exp \frac{E_d - E_c}{kT} = 6.16 \times 10^{18} \text{ cm}^{-3}$$

The free electron density is then obtained from:

$$n_o = -\frac{N^*}{2} + \sqrt{\frac{(N^*)^2}{4} + N^* N_d} = 1.94 \times 10^{17} \text{ cm}^{-3}$$

As a result 97.0 % of the donors are ionized

- b) Since we are now dealing with *p*-type material we have to recalculate N^*

$$N^* = \frac{N_v}{4} \exp \frac{E_v - E_a}{kT} = 8.08 \times 10^{15} \text{ cm}^{-3}$$

where the factor 4 is due to the doubly degenerate valence band. The free hole density is then obtained from:

$$p_o = -\frac{N^* + N_d}{2} + \sqrt{\frac{(N^* + N_d)^2}{4} + N^* (N_a - N_d)} \\ = 5.52 \times 10^{16} \text{ cm}^{-3}$$

which is identical to (2.6.42) except that the donor and acceptor densities have been exchanged. Only 2.76 % of the acceptors are ionized while all donors are ionized.
